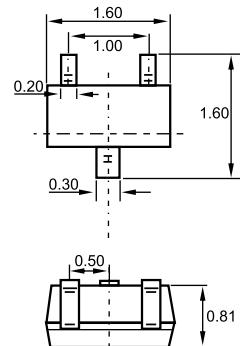




## Features

- ✧ Low forward voltage drop.
- ✧ Fast switching.
- ✧ Ultra-small surface mount package.
- ✧ PN junction guard ring for transient and
- ✧ ESD protection.

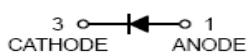
**SOT-523**



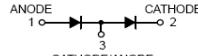
## Applications

Dimensions in inches and (millimeters)

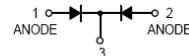
- ✧ General purpose switching application.



BAS40T



BAS40-04T



BAS40-05T



BAS40-06T

## Ordering Information

Type No.	Marking	Package Code
BAS40T	43	SOT-523
BAS40-04T	44	SOT-523
BAS40-05T	45	SOT-523
BAS40-06T	46	SOT-523

**MAXIMUM RATING** @  $T_a=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Value	Units
$V_{RRM}$	Peak repetitive reverse voltage		
$V_{RWM}$	Working peak reverse voltage	40	V
$V_R$	DC reverse voltage		
$V_{R(RMS)}$	RMS reverse voltage	28	V
$I_F$	Forward continuous voltage	200	mA
$I_{FSM}$	Non-repetitive peak forward surge current @ $t=1.0\text{s}$	600	mA
$P_d$	Power dissipation	150	mW
$R_{\theta JA}$	Thermal resistance junction to ambient	833	°C/W
$T_j, T_{stg}$	Junction and Storage Temperature	-65~150	°C

**ELECTRICAL CHARACTERISTICS @  $T_a=25^\circ\text{C}$  unless otherwise specified**

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	$V_{(BR)R}$	$I_R=10\mu\text{A}$	40		V
Leakage current	$I_R$	$V_R=30\text{V}$		200	nA
Forward voltage	$V_F$	$I_F=1.0\text{mA}, t_p < 300\mu\text{s}$ $I_F=40\text{mA}, t_p < 300\mu\text{s}$		380 1000	mV
Typical total capacitance	$C_T$	$V_R=0\text{V}, f=1\text{MHz}$		5.0	pF
Reverse recovery Time	$t_{rr}$	$I_F=I_R=10\text{mA}, I_{rr}=0.1*I_R, R_L=100\Omega$		5.0	ns

**TYPICAL CHARACTERISTICS @  $T_a=25^\circ\text{C}$  unless otherwise specified**
